

Ammonia Room Temperature Gas Sensor Using Different TiO₂ Nano-structure

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Research Article

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Abstract

In this study, TiO₂ Nano-structure were synthesized by three different processes including nanowires, nanoparticles and thin- films. The morphology and crystal structure of the three different TiO₂ structures deposited on quartz glasses were characterized by XRD, SEM and FTIR. It has been found that nanowires and nanoparticles showed only the anatase phase while the thin-film exhibited both anatase and rutile phases. The three TiO₂ Nano-structures were then used to fabricate gas sensors for ammonia (NH₃) detection at different concentrations and various conditions. The samples fabricated with thin-film TiO₂ towards 50 ppm NH₃ showed a response value of 5% at room temperature, whereas the other two samples exhibited much higher values towards similar condition NH₃ at room temperature. Samples with nanowires showed a three-fold increase and samples with nanoparticles exhibit a two-fold increase in response value. We have found that the response of all samples increases with elevating the operating temperature up to 200°C. Increasing the operating temperature improved the nanoparticle sensing conditions more than the other two samples. The samples using nanoparticles showed a 33% increase in response towards 50 ppm NH₃ at 200°C compared to the samples with thin films at similar conditions. Further, response and recovery time were investigated and reported in this study.

Introduction

There is a vast investigation in the literature for gas sensor materials including semiconductor [1], Metal Oxide-Based [2], Nano fibers [3], Carbon-Based [4]. However, there is a lack of information for NH₃ sensing using different TiO₂ nanostructures.

Nanostructured Materials, having the size in the range from 1 nm to 100 nm, showing amazing properties that differ from conventional materials [5]. In gas sensor field, porosity and a high surface-to-volume ratio in order to emphasize surface effects are essential to obtain the properties appropriate for gas-sensing applications [1, 6-7]. The two properties play a more important role in nanostructure materials [8]. In addition, the electrical properties of such nanostructured materials on a high aspect ratio may be easily changed in the presence of small amounts of gas molecules [9].

Semiconductor metal oxide (SMO) gas sensors are the most popular because of quick and precise responses [1, 10]. TiO₂ has a wide range of applications as gas sensors in a medical controller and particular environment [11, 12]. Improvements in gas sensing parameters have been reported in various titanium Nano-structures [13]. In Nano-structure sensors, drift, molecular, and surface mechanisms which are reported very commonly, make them more sensitive adequate at room temperature [14, 15].

The change in conductivity in metal oxide gas sensors such as Titanium dioxide (TiO₂) is due to two factors: the change in carrier density or the change in bending of the energy band structure in the presence of gas [16]. The sensor mechanism of the bulk TiO₂ has been modeled in various forms [17-21]. Generally, in a non-porous structure, gas molecules are decomposed by physical absorption followed by

chemical reaction with oxygen atoms on the semiconductor surface. The result of this interaction with the surface reduces oxygen and thus increasing the number of free electrons in the oxide body [22].

It was shown that the sensing property of TiO_2 similar to semiconductor material increases as the size of the grains decreases [23]. On the strength of this consideration nanostructured TiO_2 can be a good candidate for gas sensors.

Due to the reduction of grain size TiO_2 , the sensitive layer allows high surface-volume ratio and results in a high level of sensitivity and selectivity [1, 24].

Ammonia with the formula NH_3 , the most important hydrogenated compound in nitrogen, is naturally derived from the decomposition of nitrogenous organic matter [25, 26]. It is a colorless gas with an extremely nasty taste that is also tearful and suffocating [27]. Therefore, it is important to detect a very small volume of this gas in the industry.

In this paper, three different structures of TiO_2 nanostructures used as an ammonia gas sensor at room temperature ($25\text{ }^\circ\text{C}$) are examined: I. Thin film II. Nanowire III. Nanoparticles. Different methods of synthesis and characterization to optimize the growth process are examined and tested. The measurement methods were applied to all the three structures.

Experimental

A. Growth of TiO_2 Nanoparticles by Sol-Gel Method

Different sol-gel methods for synthesis have been proposed including [28, 29]. It has been reported that different phases of the formation of anatase and rutile are the result of different growth methods [30]. In this study, TiO_2 was synthesized by the sol-gel method in various alcohol solvents [31]. It should be noted that the Changes in photocatalytic properties, thermal stability, electrical properties and nanoparticle dimensions are the result of these variations synthesis.

In this study, two different solvents were used for the growth of titanium dioxide nanoparticles by sol-gel method, 0.75 milliliters of Titanium isopropoxide ($\text{Ti}\{\text{OCH}(\text{CH}_3)_2\}_4$) were dissolved in 1.5 milliliter alcohol and 1.5 milliliter Acetic acid (CH_3COOH) solution by continuous magnetic stirring for 30 minutes as well as 0.3 grams of Polyvinylpyrrolidone ($\{\text{C}_6\text{H}_9\text{NO}\}_n$) were dissolved in Alcoholic solvent in similar situations. The two solvents were mixed for 120 minutes. Finally, the mixture was deposited on the quartz substrate by spin coating. To complete the growth processes the sample was placed in the oven at a temperature of $450\text{ }^\circ\text{C}$ for one hour. The final thickness of the sample was measured as 100 nm. The morphology and microstructure of nanoparticles of titanium dioxide were examined by SEM. As shown in the Fig. 1 the film exhibit structure pore which is important for gas sensing application.

B. Growth of TiO₂ Nanowire by hydrothermal Method

Since nanowire and nanotube of titanium dioxide have a high share of commercial production [32], in various investigations, several methods have been developed for the fabrication of these nanowires, including laser ablation [33], solution–liquid–solid [34], arc discharge [35], vapor–liquid–solid [34], and template-based synthetic approaches [36], which have all been proved to be successful methods for various methods. However, all of the methods used in this study are either physical template or catalyst materials, which may cause contamination in the samples. Therefore, it is believed to use a hydrothermal synthesis nanowire without using preformed templates or catalyst materials [37]. Therefore, the growth of titanium dioxide nanowires by a hydrothermal method is one of the attractive and widely used methods. In this study the growth of nanowires, TiO₂ has been performed using 0.3 molar Titanium isopropoxide were mixed with 0.1 molar Ethanolamine in a magnetic stirrer for 2 hours. Further 10 molar Sodium hydroxide (NaOH) was dropped into the mixture and it was put back on the magnetic stirrer for one hour. The resulting solution was held for 20 hours at 150 °C. After this period, the solution was returned to room temperature naturally. Obtained sediment was centrifuged and washed several times with distilled water and was put at 60 °C to dry for 24 hours. Dried sediment was collected and put in 0.1 molar hydrochloric acid (HCL) solution for one hour. The white color sediment was collected by centrifugation and washed several times again with distilled water and ethanol (C₂H₆O) and dried at 100 °C for one hour. Finally, nanowire titanium dioxide was obtained by baking sediment at 500 °C in air for another hour. Fig. 2 shows the SEM micrograph of the sample grown with the method mention above.

C. Growth of TiO₂ thin-film by sputtering Method

In this method, The TiO₂ Nano composite was fully grown by RF sputtering technique on the quartz substrate. To prepare Target, ten grams of TiO₂ powder was mixed with polyvinyl alcohol ([CH₂CH (OH)]_n). The mixture was baked at 1000 °C. Sputtering is performed at a vacuum pressure of 2.5 mTorr and a surface temperature of approximately 200 °C. RF power, base pressure and argon flow rate have been optimized to 500(W), 1.33×10⁻⁵(Pa) and 30 (sccm) respectively. As the sputtering time changes, the thickness of the TiO₂ layer changes from 10 to 100 nm. To crystalline, the TiO₂ thin films of varying thickness were exposed to oxygen at 600 °C. Fig. 3 shows two samples of SEM micrographs of titanium dioxide by the sputtering method with varying thicknesses. In this study, we used sputtered TiO₂ film with 20 nm thickness.

D. Sensing Measurements

For fabrication gas sensor devices the TiO₂ samples were fabricated in 1×1 cm dimensions. Growth processes for each synthesis sample were adjusted to be about 20 nm in thickness for all three samples in the present study.

For electrical contact, the Gold (Au) electrode was deposited using sputtering. The Au thickness was set to 50 nm. Silver paint was used to connect the sample to the measuring circuit. The electrical response of the TiO₂ was tested toward several ppm NH₃ at room temperature. According to the generally acknowledged definition [38], the response of a sensor to a given concentration [gas] of an oxidizing/reducing, gas is:

$$response = \frac{|R_{gas} - R_{air}|}{R_{air}} \cdot \frac{1}{[gas]} \quad (1)$$

R_{air} is the resistance of two ends of the terminal before gas exposure in stable mode and R_{gas} is exact resistance after gas exposure. We set the [gas] for 50 ppm, 100 ppm and 200 ppm one, two and four respectively.

The measured resistance (R_{air}) for thin-film, nanoparticle and nanowire are 0.45M, 1.1M and 0.54M ohm, respectively.

Ammonia gas is prepared by heating a mixture of ammonium chloride and slaked lime in the ratio of 2 : 3 by mass and passing the gas through the drierite. Moist ammonia gas is dried over quilkime (CaO). Nitrogen (N₂) gas flow was used to control the concentration of ammonia gas. N₂ gas was flowing into the gas chamber up to the system reached a steady-state situation. The concentration of ammonia gas has been determined by the ratio of the flow rate of ammonia and nitrogen gases entering to the chamber.

Results And Discussion

A. Structure characterization

Fourier-transform infrared spectroscopy (FTIR) and X-ray diffraction (XRD) were used to characterize three Nano-structure samples.

FTIR (JASCO, model: 460 Plus) studies of the TiO₂ grown in all three structures showed the characteristics of the formation of high purity product with the least amount of impurity. Fig. 4 shows a sequence of FTIR spectra for TiO₂ nanowire, nanoparticle and thin-film in the range of 500–4000 cm⁻¹. As reported in the literature [39] the peaks at 3440 cm⁻¹ in the spectra are due to the stretching and bending vibration of the -OH group. The peaks at 1620 cm⁻¹ show stretching vibrations of Ti-O-Ti. Further, the peak observed at 690 cm⁻¹ is due to the vibration of the Ti-O-O bond. Therefore, it is obvious that The FTIR spectra clearly exhibit the presence of Ti-O bonds in all the three samples.

Moreover, XRD (Inel, model: EQUINOX3000) was conducted to determine the phase analysis of each sample. In our XRD equipment monochromatic optic Ka1 or Ka1/2 were used. Fig. 5 presents the XRD pattern of the synthesized samples where the peaks of anatase and rutile nanoparticles are well

recognized. As shown in Fig. 5 both nanoparticle and nanowire samples show only the anatase phases, but the rutile phase is observed only in a thin-film sample. XRD pattern specifies the phases and sizes of crystalline materials, providing a determination of the ratio of the anatase phase to the rutile phase in the TiO₂ Nano-structures. Three peaks were considered for the study, and using the Debye-Scherrer formula, the grain size was calculated for all three peaks. From Fig. 5, considering the peak Full Width at Half Maximum (FWHM), the average particle size is calculated. This size was calculated for nanowire and nanoparticles samples less than 100 nm while for thin-film sample more than 100 nm was obtained. Peaks in XRD pattern at $2\theta=25^\circ$ (101) and $2\theta=48^\circ$ (101) indicated the presence of the anatase phase while peaks at $2\theta=27.5^\circ$ (110) demonstrated the occurrence of rutile phase. All three peaks suggest that the prepared samples are in a hexagonal structure. The pattern matches well with the standard JCPDS files # 21-12729 [40]. The intensity of XRD peaks of the nanowire and Nano-particle TiO₂ samples shows that the formed nanoparticles are crystalline and broad diffraction peaks indicate small size crystallite. Since in the present study, the sensors were tested at room temperature, there is no concern about the phase change.

B. Electrical measurement

Gas sensing measurements have been conducted under constant temperature conditions at room temperature with different ammonia concentrations.

For measurements and tests of TiO₂ samples the circuit shown in Fig. 6 is used. The silver paint was used to connect the external contact to Au electrodes. The electrical characteristics of the TiO₂ sensors were obtained from the I-V curve of the electrodes junction measured by the KEITHLEY 228A voltage/current source and Sanwa PC7000 Handheld multimeter. To dynamic gas sensing measurements in this investigation, studied devices were placed in a chamber with a continuously gas flow. The humidity control was performed using silica gel. Besides, temperature and humidity sensors are placed in the sensing chamber for online monitoring.

In the first step, the response of the samples toward the different amounts of NH₃ gas has been measured. As shown in Fig. 7 the highest response was observed in the nanowire TiO₂ sample toward different concentrations. The response to ammonia gas in the nanoparticle TiO₂ was very close to the response of the nanowire sample, but the response of the thin-film TiO₂ sample was approximately half that of the nanowire TiO₂ sample. As shown in the SEM pictures (Fig. 1 and Fig. 2) in the nanowire and nanoparticle samples with high porosity, a larger surface-to-volume ratio is seen because the surface arrangement of atoms is slightly different from that of the body [41] and so surface oxygen molecules are easily removed from the surface and create oxygen vacancies [40]. Further, as it is shown in Fig. 7 when the inlet NH₃ gas concentration increased, the response also increased in all three samples. At a high concentration of 200 ppm, the percentage of response differences between the thin-film sample and the other two samples was less compare to lower NH₃ concentration. This phenomenon implies that at

higher concentrations of gas, other defects such as interstitial ions Ti^{3+} and Ti^{4+} in the titanium dioxide lattice play a role in the gas sensing mechanism [42]. The amount of oxygen vacancies in the TiO_2 at the room temperature is not sufficient for gas sensing. But, in Nano-structure TiO_2 , due to the presence of a very large volume to surface ratio, there is a lot of surface oxygen with dangling bonds, which can be absorbed by ammonia molecules and extracted from TiO_2 . This process can lead to the release of carriers in titanium dioxide and thus, a change in the Fermi level. When surface of Nano-structures TiO_2 is exposed to gas molecules, the oxyanions react with the ammonia molecules and deliver a large number of carries to the grains [43]. In a non-porous structure, gas molecules react by physically and then chemically adsorbed on the oxide semiconductor surface, decomposed by semiconductor oxygen atoms. The result of this surface interaction is the reduction of oxygen, resulting in an increase in the number of free electrons in the oxide body, which increases conductivity [44]. In the polycrystalline structure, the determining factor for the conduction of the sensitive layer is the potential barrier height between the grains. At the grain level, oxygen can be absorbed to the grain surface in forms of O^{2-} , O^- and O_2^- creating a potential barrier at the grain boundaries. So typically, the semiconductor oxide sensor properties increase with decreasing grain size [23]. Therefore, nanowire and nanoparticle samples that have smaller grain size boundaries will show higher response.

The change in conductivity in metal oxide gas sensors is due to two factors: change the carrier density or bending of energy bands in the presence of gas [1]. The speed of carrier response or bending change was examined after applying the gas to the surface. Fig. 8 shows response and recovery times after inserting the NH_3 gas and disconnecting the flow of the gas. Response time for the nanowire and nanoparticle samples have been recorded around 40 seconds while for thin-film sample showed a response time of around 70 seconds. Recovery times in three samples were measured approximately 15 seconds. As discussed earlier the nanowire and nanoparticle films exhibited more pores than thin films. So due to the greater porosity of the nanowire and the nanoparticle samples, the number of molecules reaching the surface increase and create lower Response Times. However, porosity does not have much effect on recovery time.

In the nanocrystals, the interaction of the gas molecules with other molecules like water molecules adsorbed on the surface of the grains has a greater effect on the electrical conductivity of the sensitive layer [22]. The change in the number of atoms adsorbed at the surface controls the mobility of the carriers by changing the number of distributed carriers [45]. The presence of water molecules can interfere with the gas molecules adsorbed on the surface. Two different tests were performed to accurately examine the effect of humidity.

First, the fabricated sensors considered as the humidity sensor. Humidity sensing was performed at room temperature and 760 mmHg pressure. As shown in Fig. 9 (a) the response of the samples to humidity is very low compared to ammonia gas. All three sensors showed a very small response to change in relative humidity. Most sensitivities observed for thin-film, nanoparticle and nanowire were 0.019, 0.035 and 0.034, respectively at 80% relative humidity. In this experiment dry environment is considered below 10%

relative humidity and concentration [gas] in the response equation (1) for 80% relative humidity was equal to 50 ppm. Since the response of samples is very low in the presence of different humidity, these samples cannot be a humidity sensor.

In the second experiment, changes in humidity during ammonia gas sensing were investigated. Fig. 9(b) shows the changes in the response of the different samples versus humidity. The response values have been obtained from the results shown in Fig. 7. As shown in Fig. 9(b) the response decrease slightly with increasing humidity up to 60%. Though the response decreases drastically above 60% of humidity's.

As shown in Fig. 9(b) humidity effect toward 50 ppm NH_3 gas response is less than 3% up to 60% relative humidity for samples. Also the sensor response to 10-90 relative humidity has experimented for all three samples.

To characterize the response of the three sensors at the higher operating temperature we measured the senility of the samples at various temperatures from 25 °C to 200 °C. As reported in the literature [42] the sensing mechanism TiO_2 change with temperature. These can be due to the different oxygen densities in TiO_2 with various temperatures. It is believed that higher temperatures create lattice defects in TiO_2 [46]. Oxygen vacancies at higher temperatures diffused rapidly with high mobility into the TiO_2 body as so these define the conductivity of TiO_2 sensors [47]. As Fig. 10 illustrates, increasing the temperature to around 200 °C resulted in a significant increase in response. This increase was observed more than 3.5 times in the nanoparticle sample compared to the sample operated at room temperature. Further, the effect of temperature on the response of the nanoparticle sample was greater than that of the nanowire sensor. The difference is because the nanoparticle sample has a higher porosity than the other films increasing the properties of the body O_2 in the sensing mechanism.

To consider the thermal and electrical stability of the fabricated samples, two tests were performed without inserting gas into the test chamber: First, we applied a voltage of 40V DC for 24 hours [48] followed by testing the samples in an oven at 400 °C for 8 hours [1]. After the tests, samples left over for three months under normal room conditions. Gas sensing tests were performed on the samples again. As shown in Fig. 11 the results showed that the nanowire sample was more stable than the other samples. Significant differences were observed in the response of the nanoparticle and thin-film in the response time and the recovery time for the fabricated samples and those tested after three months. Condition 1 shows the results of the response just after the fabrication of TiO_2 and using Condition 2 exhibits the results obtained after 3 months.

Conclusion

In this study, three different structures of titanium dioxide Nano-structure of a nanowire, nanoparticle and thin-film were fabricated for ammonia gas sensing applications. The growth of the nanowire, nanoparticle and thin-film of TiO_2 structures have been conducted on quartz glasses using hydrothermal, sol-gel and RF sputtering, respectively. The structures of the fabricated samples were examined by SEM

micrograph, FTIR characterization and XRD pattern and so the correct growth and formation of the TiO₂ lattice were confirmed. From the results obtained in this study, we may conclude that the nanowire samples operated at room temperature exhibit more sensing response toward low NH₃ conditions. Moreover, higher electrical and thermal stability were also compared to the other two samples. Finally, we confirmed the nanowire samples indicate a much higher response and stability than the other two sensors.

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Declarations

Declaration of interests-

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

Figures

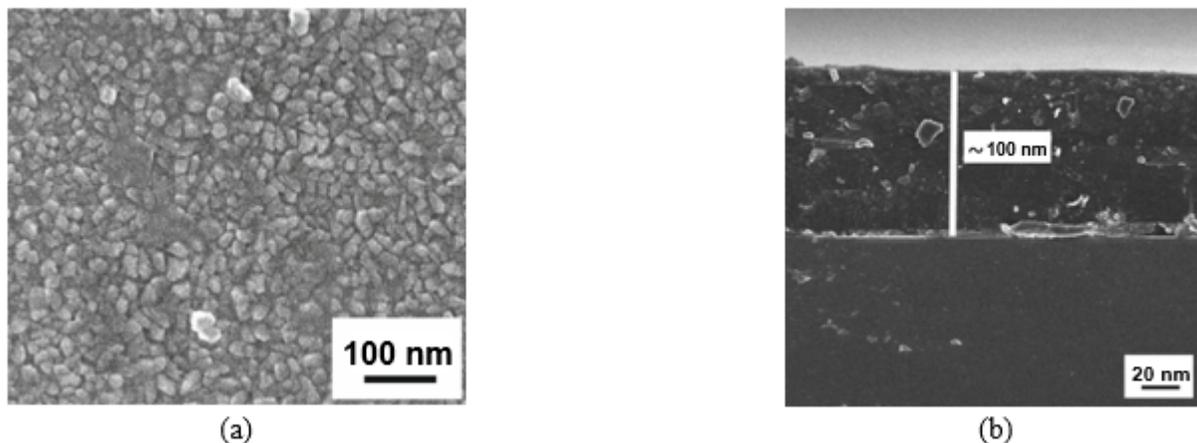


Figure 1

SEM micrograph of titanium dioxide film prepared by sol-gel method a) from top and b) cross section.

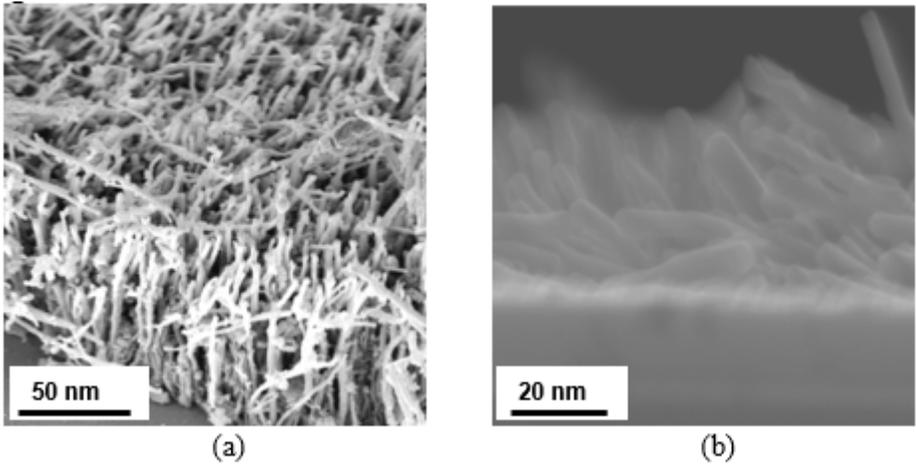


Figure 2

(a) Top view and (b) cross-section SEM micrograph of titanium dioxide film prepared by hydrothermal method.

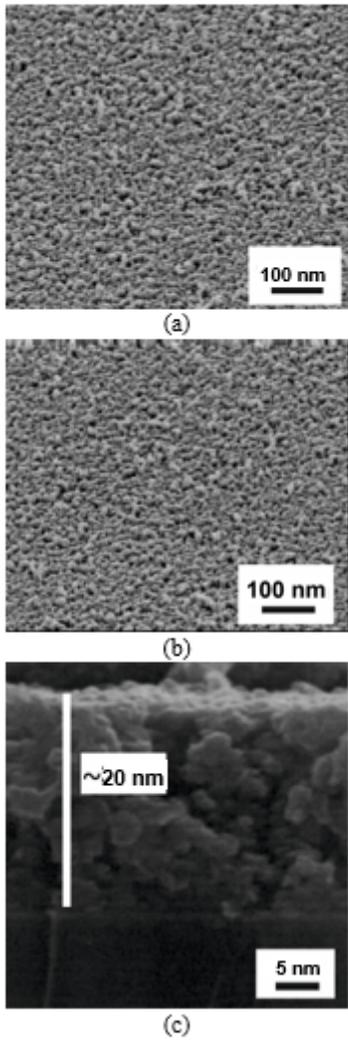


Figure 3

SEM micrograph of titanium dioxide film by a sputtering method with (a) 20 nm thickness from the top, (b) 10 nm thickness from the top and (c) cross-section of TiO₂ with 20 nm thickness.

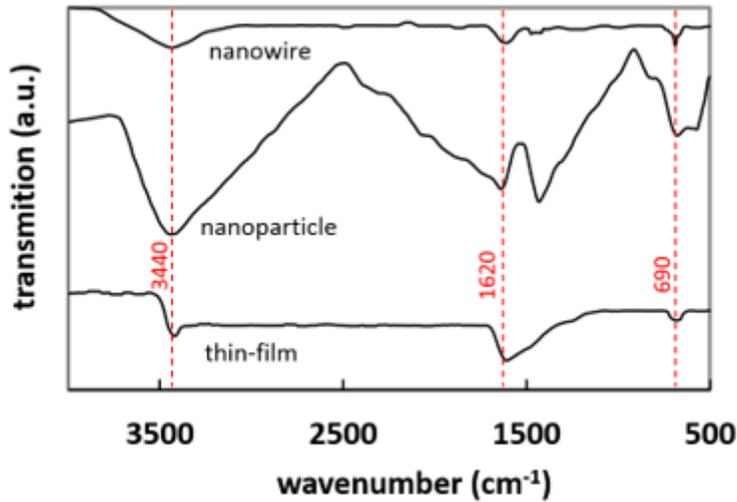


Figure 4

Fourier-transform infrared (FTIR) spectra for three structures of titanium dioxide Nano-structures.

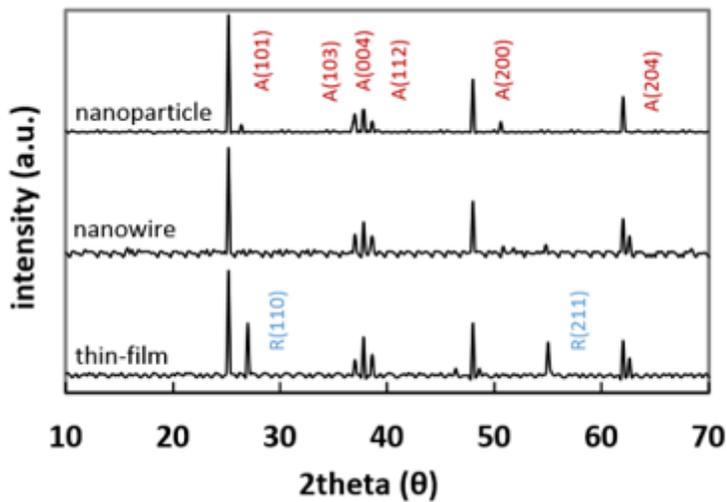


Figure 5

X-ray diffraction (XRD) pattern of synthesized structures for titanium dioxide Nano-structures.

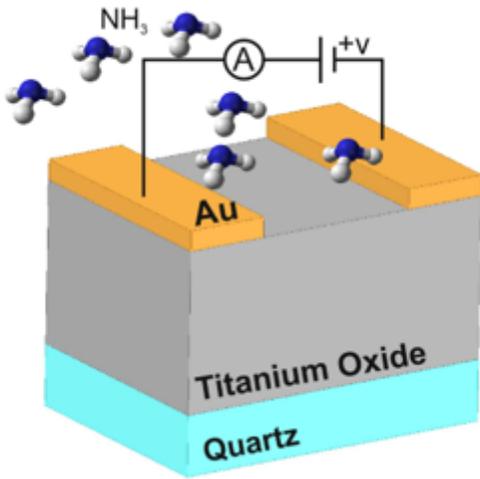


Figure 6

The configuration used for response measurement.

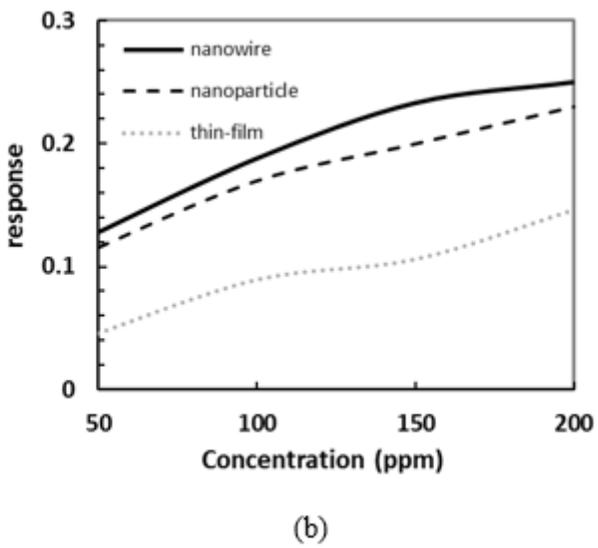
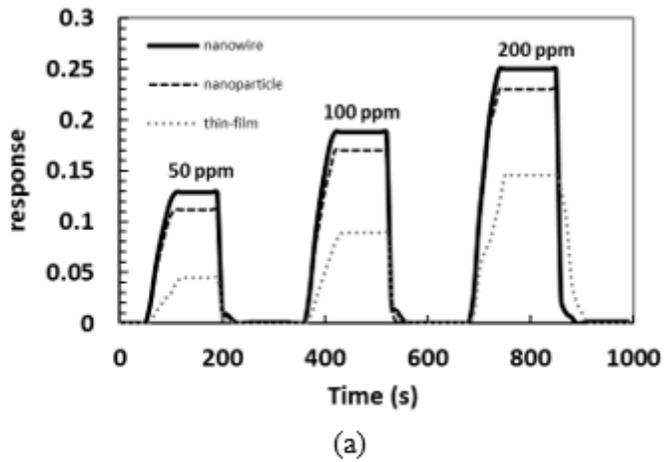


Figure 7

a) Response of nanowire, nanoparticle and thin-film of TiO₂ at different concentrations of ammonia gas at room temperature. b) Response vs. ammonia concentration.

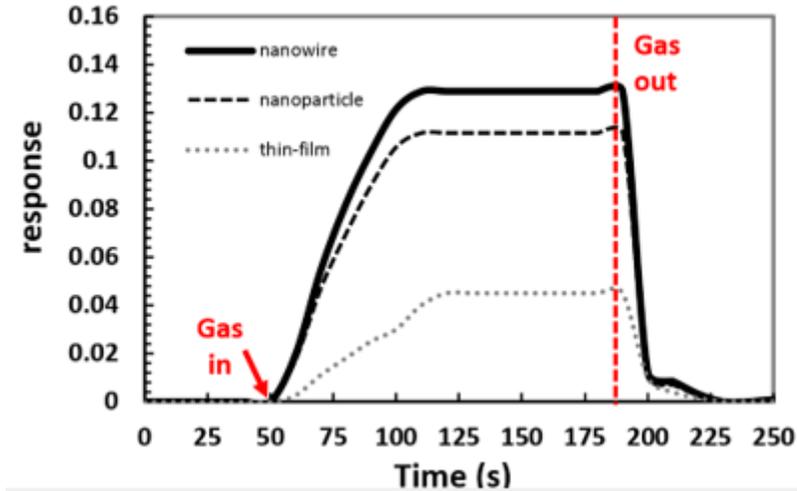
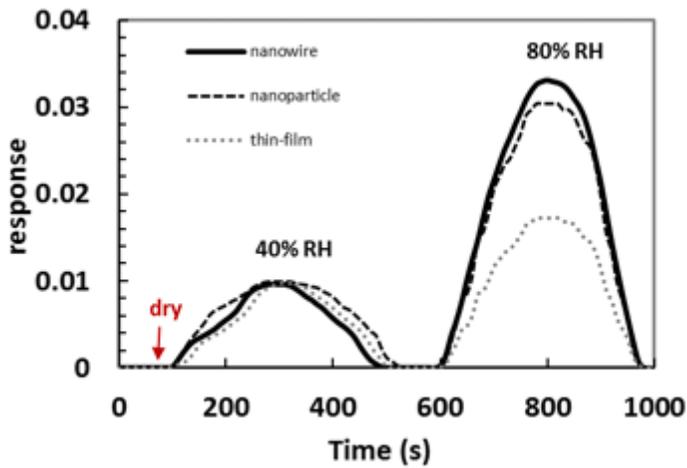
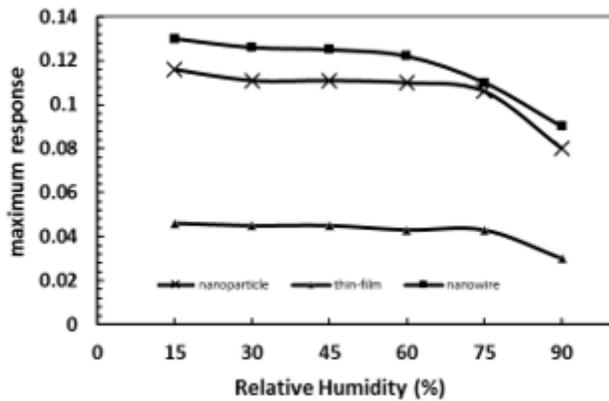


Figure 8

Response of nanowire, nanoparticle and thin-film of TiO₂ at 50 ppm concentrations of ammonia gas operated at room temperature.



(a)



(b)

Figure 9

a) The response of nanowire, nanoparticle and thin-film of TiO₂ at different relative humidity at room temperature. b) Response vs. relative humidity at 50 ppm concentrations of ammonia gas at room temperature and 760 mmHg.

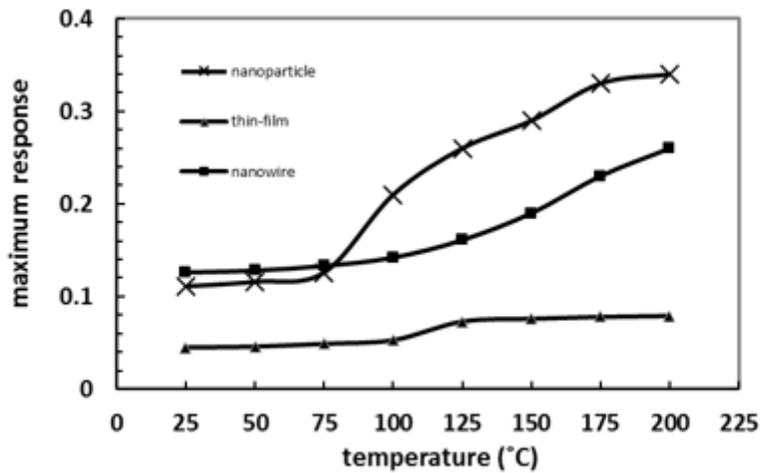


Figure 10

The response of nanowire, nanoparticle and thin-film of TiO₂ vs. temperature at 50 ppm concentration of ammonia gas.

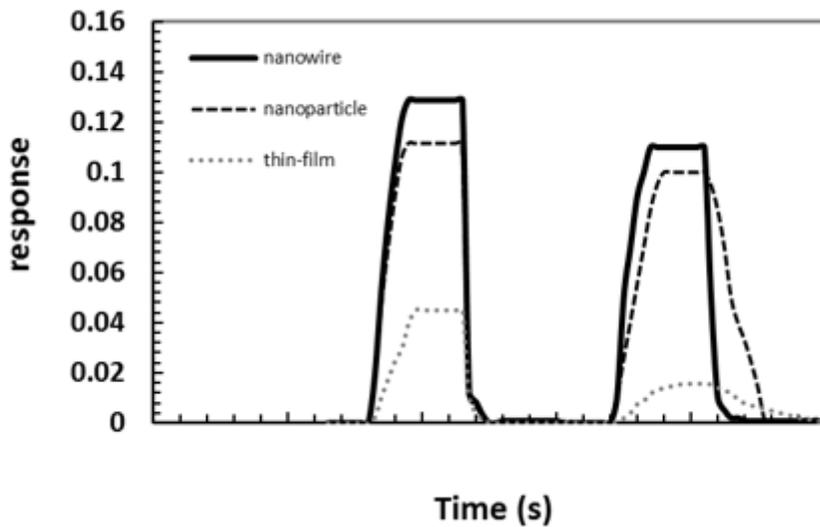


Figure 11

Response of nanowire, nanoparticle and thin-film of TiO₂ at 50 ppm concentration of ammonia gas at two different test conditions. Condition 1: Just after sensor fabrication. Condition 2: After 3 months of fabrication and under 40V voltage and 400 °C temperature.